



ADS1259-Q1 SLASE20-MARCH 2014

ADS1259-Q1 Automotive, 14.4-kSPS, 24-Bit Analog-to-Digital Converter With Integrated Low-Drift Reference

Features 1

- Qualified for Automotive Applications
- AEC-Q100 Qualified with the Following Results:
 - Temperature Grade 1: –40°C to 125°C
 - HBM ESD Classification 2
 - CDM ESD Classification C4B
- Programmable Data Rates: 10 SPS to 14.4 kSPS
- Single-Cycle Settling Digital Filter
- High Performance:
 - 21.3 ENOB at 1.2 kSPS
 - INL: 3 ppm
 - Offset Drift: 0.05 µV/°C
 - Gain Drift: 0.5 ppm/°C
- Internal Reference: 2.5 V, 10 ppm/°C Drift
- Internal 2% Accurate Oscillator
- Input Signal Out-of-Range Detection
- Optional Checksum and Redundant Data-Read Capability to Augment Data Integrity
- SPI[™]-Compatible Interface, Mode 1
- Analog Supply: 5 V or ±2.5 V
- Digital Supply: 2.7 V to 5 V

Applications 2

- Automotive Power Train
- **Electrical Vehicles**

3 Description

Tools &

Software

The ADS1259-Q1 is a precision, low-drift, 24-bit, analog-to-digital converter (ADC). The device can perform conversions at data rates up to 14.4 kSPS with high resolution and is therefore ideally suited to measure rapidly changing signals that have a wide dynamic range. An integrated low-noise, low-drift 2.5-V reference eliminates the need for an external voltage reference, thus reducing system cost and component count.

Support &

Community

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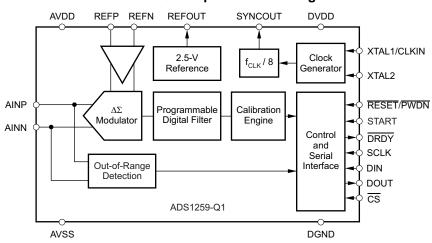
The converter uses a fourth-order, inherently stable, delta-sigma ($\Delta\Sigma$) modulator that provides outstanding noise performance and linearity. The device can use the integrated oscillator, an external crystal, or an external clock as the ADC clock source.

A fast-responding input overrange detector flags the conversion data if an input overrange event occurs. To augment data integrity in noisy automotive environments the ADS1259-Q1 offers an optional checksum byte and a redundant conversion dataread capability.

The ADS1259-Q1 consumes 13 mW during operation and less than 25 μ W when powered down. TI offers the ADS1259-Q1 device in a TSSOP-20 package with full specification from -40°C to 125°C.

Device Information

| ORDER NUMBER | PACKAGE | BODY SIZE |
|---------------|------------|-----------------|
| ADS1259QPWRQ1 | TSSOP (20) | 6,5 mm × 4,4 mm |



ADS1259-Q1 Simplified Block Diagram



Sample & Buy





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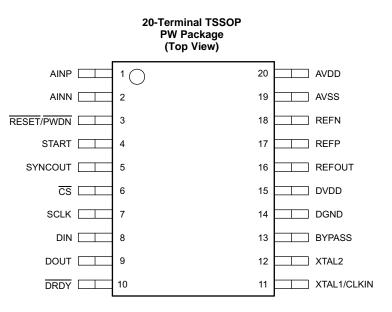
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4 Revision History

| DATE | REVISION | NOTES |
|------------|----------|-----------------|
| March 2014 | * | Initial release |



5 Terminal Configuration and Functions



Terminal Functions

| Т | TERMINAL | | DECODIDITION | | |
|-----|-------------|----------------|--|--|--|
| NO. | NAME | ТҮРЕ | DESCRIPTION | | |
| 1 | AINP | Analog input | Positive analog input | | |
| 2 | AINN | Analog input | Negative analog input | | |
| 3 | RESET/PWDN | Digital input | Reset or power down; reset is active-low; hold low for power down. | | |
| 4 | START | Digital input | Start conversions, active-high | | |
| 5 | SYNCOUT | Digital output | Sync clock output (f _(CLK) / 8) | | |
| 6 | CS | Digital input | SPI chip-select, active-low | | |
| 7 | SCLK | Digital input | SPI clock input | | |
| 8 | DIN | Digital input | SPI data input | | |
| 9 | DOUT | Digital output | SPI data output | | |
| 10 | DRDY | Digital output | Data-ready output, active-low | | |
| 11 | XTAL1/CLKIN | Digital input | Internal oscillator: DGND External clock: clock input Crystal oscillator: external crystal1 | | |
| 12 | XTAL2 | Digital | External crystal2, otherwise no connection | | |
| 13 | BYPASS | Analog | Core voltage bypass. Connect a 1-µF capacitor to DGND. | | |
| 14 | DGND | Digital | Digital ground | | |
| 15 | DVDD | Digital | Digital power supply | | |
| 16 | REFOUT | Analog output | Positive internal reference output. Connect a 1-µF capacitor, C _{REFOUT} , to AVSS. | | |
| 17 | REFP | Analog input | Positive reference input. Connect a 1- μ F capacitor, C _{REFIN} , to REFN. ⁽¹⁾ | | |
| 18 | REFN | Analog input | Negative reference input ⁽¹⁾ | | |
| 19 | AVSS | Analog | Negative analog power supply and negative internal reference output | | |
| 20 | AVDD | Analog | Positive analog power supply | | |

(1) Leave unused reference inputs unconnected or tie to AVDD.



6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating ambient temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|--------------------------------|--|------------|------------|------|
| AVDD to AVSS | | -0.3 | 7 | V |
| AVSS to DGND | | -2.8 | 0.3 | V |
| DVDD to DGND | | -0.3 | 7 | V |
| Analog input voltage | AINN, AINP, REFN, REFP | AVSS - 0.3 | AVDD + 0.3 | V |
| Digital input voltage | CS, DIN, RESET/PDWN, SCLK, START, XTAL1/CLKIN | DGND - 0.3 | DVDD + 0.3 | V |
| Input current, continuous | Any terminal except supply terminals | -10 | 10 | mA |
| Operating junction temperature | e, TJ | -40 | 150 | °C |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 Handling Ratings

| | | MIN | MAX | UNIT |
|-----------------------------------|--|-----|-----|------|
| T _{stg} | Storage temperature range | -60 | 150 | °C |
| V (1) | Human-body model (HBM) ESD stress voltage ⁽²⁾ | -2 | 2 | kV |
| V _(ESD) ⁽¹⁾ | Charged-device model (CDM) ESD stress voltage ⁽²⁾ | -1 | 1 | kV |

(1) Electrostatic discharge (ESD) to measure device sensitivity or immunity to damage caused by assembly-line electrostatic discharges into the device.

(2) Meets or exceeds the passing level per AEC-Q100.



6.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

| | | MIN | NOM | MAX | UNIT |
|---|--|-------------------|------------|----------------------|------|
| POWER SUPPLY | | | | | |
| Analan nawar avanlı | AVDD to AVSS | 4.75 | 5.0 | 5.25 | V |
| Analog power supply | AVSS to DGND | -2.6 | -2.5 | 0 | V |
| Digital power supply | DVDD to DGND | 2.7 | 3.3 | 5.25 | V |
| ANALOG INPUTS | 1 | | | · | |
| Absolute input voltage | AINP or AINN | AVSS - 0.1 | | AVDD + 0.1 | V |
| Differential input voltage ⁽¹⁾ | $V_{(IN)} = (V_{(AINP)} - V_{(AINN)})$ | -V _{ref} | | V _{ref} | V |
| VOLTAGE REFERENCE INPUTS | | | | | |
| Reference input voltage | $V_{ref} = (V_{(REFP)} - V_{(REFN)})$ | 0.5 | 2.5 | AVDD – AVSS + 0.2 | V |
| Absolute negative reference voltage | REFN | AVSS - 0.1 | AVSS | REFP – 0.5 | V |
| Absolute positive reference voltage | REFP | REFN + 0.5 | AVSS + 2.5 | AVDD + 0.1 | V |
| EXTERNAL CLOCK SOURCES (f(CL | к)) | | | | |
| Crystal oscillator | Frequency | 2 | 7.3728 | 8 | MHz |
| Endersonal electronic | Frequency | 0.1 | 7.3728 | 8 | MHz |
| External clock | Duty cycle | 40% | | 60% | |
| DIGITAL INPUTS | | | | | |
| High-level input voltage, V _{IH} | | 0.8 DVDD | | DVDD | V |
| Low-level input voltage, VIL | | DGND | | 0.2 DVDD | V |
| TEMPERATURE RANGE | | | | | |
| Operating ambient temperature, T _A | | -40 | | 125 | °C |

(1) Excluding the effects of offset and gain error.

6.4 Thermal Information

| | THERMAL METRIC ⁽¹⁾ | PW (20 TERMINALS) | UNIT |
|-----------------------|--|----------------------|------|
| R _{θJA} | Junction-to-ambient thermal resistance | 86.9 | °C/W |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 21 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 39.1 | °C/W |
| Ψ _{JT} | Junction-to-top characterization parameter | 0.8 | °C/W |
| Ψ _{JB} | Junction-to-board characterization parameter | 38.4 | °C/W |
| R _{0JC(bot)} | Junction-to-case (bottom) thermal resistance | N/A | °C/W |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



6.5 Electrical Characteristics

Minimum and maximum specifications are at $T_A = -40^{\circ}$ C to 125°C. Typical specifications are at $T_A = 25^{\circ}$ C, AVDD = 2.5 V, AVSS = -2.5 V, DVDD = 3.3 V, external $f_{(CLK)} = 7.3728$ MHz, external $V_{ref} = 2.5$ V, and $f_{(DATA)} = 60$ SPS (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|---|----------|--------------|-----------|-------------------|
| ANALOG INPUTS | | | | | |
| Differential input impedance | | | 120 | | kΩ |
| Common-mode input impedance | | | 500 | | kΩ |
| SYSTEM PERFORMANCE | | | | | |
| Resolution (no missing codes) | | 24 | | | Bits |
| Data rate, f _(DATA) | | 10 | | 14,400 | SPS |
| Noise (input referred) | Shorted inputs, See SBAS424 for more information. | | 0.7 | | μV _{RMS} |
| Integral nonlinearity, INL | Best-fit method | -10 | ±3 | 10 | ppm |
| Offset voltage (input referred) | | -250 | ±40 | 250 | μV |
| Offset voltage after calibration ⁽¹⁾ | | | ±1 | | μV |
| Offset drift | $T_A = -40^{\circ}C$ to 125°C | | 0.05 | 0.25 | µV/°C |
| Gain error ⁽²⁾ | | -0.5% | ±0.05% | 0.5% | |
| Gain error after calibration ⁽¹⁾ | | | ±0.0002% | | |
| Gain drift | $T_A = -40^{\circ}C$ to 125°C | | 0.5 | 2.5 | ppm/°C |
| Normal-mode rejection ratio, NMRR | | | See SBAS424. | | |
| Common-mode rejection ratio, CMRR | 60 Hz, ac ⁽³⁾ | 100 | 120 | | dB |
| AVDD, AVSS power-supply rejection ratio, PSRR | 60 Hz, ac ⁽³⁾ | 85 | 95 | | dB |
| DVDD power supply-rejection ratio, PSRR | 60 Hz, ac ⁽³⁾ | 85 | 110 | | dB |
| OUT-OF-RANGE DETECTION | | | | | |
| Threshold level | AVSS + 150 mV \leq V _(AINP) , V _(AINN) \leq AVDD - 150 mV | | ±105 | | %FSR |
| Threshold level accuracy | AVSS + 150 mV \leq V _(AINP) , V _(AINN) \leq AVDD - 150 mV | | ±0.5 | | %FSR |
| VOLTAGE REFERENCE INPUTS | (AINP), (AINN) = | | | | , |
| Average reference input current | $AVSS \le V_{(REFP)}$, $V_{(REFN)} \le AVDD$ | | 350 | | nA |
| Average reference input current drift | ······································ | | 0.2 | | nA/°C |
| INTERNAL VOLTAGE REFERENCE | | | 0.2 | | |
| Reference output voltage | V _(REFOUT) = (REFOUT – AVSS) | | 2.5 | | V |
| Accuracy | $T_{A} = 25^{\circ}C$ | -0.4% | 2.0 | 0.4% | • |
| Temperature drift | $T_{A} = -40^{\circ}C \text{ to } 125^{\circ}C$ | 0.470 | 10 | 40 | ppm/°C |
| Drive current (sink and source) | | -10 | 10 | 10 | mA |
| Load regulation | | 10 | 10 | 10 | μV/mA |
| Turn-on settling time | $\pm 0.001\%$ settling, C _{REFIN} = 1 µF, C _{REFOUT} = 1 µF | | 10 | | s |
| Long-term stability | 0 to 1000 hours | | 70 | | ppm |
| Thermal hysteresis | | | 30 | | ppm |
| CLOCK SOURCE (f _(CLK)) | | | | | ppm |
| Internal oscillator frequency | | | 7.3728 | | MHz |
| Internal oscillator accuracy | | -2% | ±0.2% | 2% | IVII IZ |
| External crystal oscillator start-up time ⁽⁴⁾ | 18-pF load capacitors | -270 | ±0.2 % | 2 /0 | ms |
| | | | 20 | | 1115 |
| DIGITAL INPUTS AND OUTPUTS (DVDD = 2.7 V | | | | | |
| High-level output voltage, V _{OH} | $I_{OH} = 1 \text{ mA}$ | 0.8 DVDD | 0.75 DVDD | | V |
| | $I_{OH} = 8 \text{ mA}$ | | 0.75 DVDD | 0.0.01/05 | |
| Low-level output voltage, V _{OL} | $I_{OL} = 1 \text{ mA}$ | | 0.0.01/00 | 0.2 DVDD | V |
| here at he reference in | I _{OL} = 8 mA | | 0.2 DVDD | | |
| Input hysteresis | | | 0.1 | | V |
| Input leakage | 0 < V _(DIGITAL INPUT) < DVDD | -10 | | 10 | μA |

(1) Calibration accuracy is on the level of noise (signal and ADC), reduced by the effect of 16-reading averaging.

(2) Excludes internal reference error.

(3) f_(DATA) = 14.4 kSPS. Placing a notch of the digital filter at 60 Hz (setting f_(DATA) = 10 SPS or 60 SPS) further improves the commonmode rejection and power-supply rejection of this input frequency.

(4) External crystal start-up time can vary with crystal manufacturer and over temperature.



Electrical Characteristics (continued)

Minimum and maximum specifications are at $T_A = -40^{\circ}$ C to 125°C. Typical specifications are at $T_A = 25^{\circ}$ C, AVDD = 2.5 V, AVSS = -2.5 V, DVDD = 3.3 V, external $f_{(CLK)} = 7.3728$ MHz, external $V_{ref} = 2.5$ V, and $f_{(DATA)} = 60$ SPS (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN TYP | MAX | UNIT |
|---|--|---------|-----|------|
| POWER SUPPLY | | | | |
| | Operating (internal reference enabled) | 2.3 | 5 | mA |
| Absolute analog supply current (AVDD, AVSS) | Standby mode (internal reference enabled) | 200 | | |
| | Standby mode (internal reference disabled) | 1 | | μA |
| | Power-down mode | 1 | | |
| | Operating (internal oscillator ⁽⁵⁾) | 500 | 700 | |
| Digital supply current (DVDD) | Standby mode (internal oscillator) | 160 | 300 | μA |
| | Power-down mode (external CLKIN, SCLK stopped, digital inputs maintained at $V_{\rm IH}$ or $V_{\rm IL}$ voltage levels) | 1 | 10 | |
| | Operating (internal reference enabled, internal oscillator) | 13 | 28 | |
| Power dissipation | Standby mode (internal reference enabled, internal oscillator) | 1.5 | | mW |
| | Standby mode (internal reference disabled, internal oscillator) | 0.5 | | |
| | Power-down mode | 10 | | μW |

(5) Internal oscillator current: 40 µA (typ.)

7 Residue

See SBAS424 for any information on the ADS1259-Q1 device that is not covered in the foregoing sections.



8 Device Documentation and Support

8.1 Trademarks

SPI is a trademark of Motorola.

All other trademarks are the property of their respective owners.

8.2 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.



9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



6-Feb-2020

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package | Pins | Package | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|---------|----------------------------|------------------|--------------------|--------------|----------------|---------|
| | (1) | | Drawing | | Qty | (2) | (6) | (3) | | (4/5) | |
| ADS1259QPWRQ1 | ACTIVE | TSSOP | PW | 20 | 2000 | Green (RoHS & no Sb/Br) | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | AD1259Q1 | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF ADS1259-Q1 :



PACKAGE OPTION ADDENDUM

6-Feb-2020

Catalog: ADS1259

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

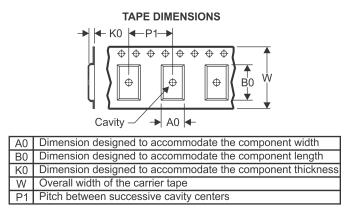
PACKAGE MATERIALS INFORMATION

www.ti.com

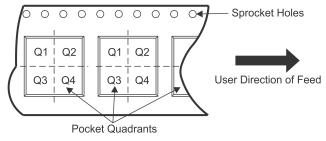
Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| ADS1259QPWRQ1 | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.1 | 1.6 | 8.0 | 16.0 | Q1 |

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

12-Mar-2016



*All dimensions are nominal

| Device | Device Package Type | | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) | |
|---------------|---------------------|----|------|------|-------------|------------|-------------|--|
| ADS1259QPWRQ1 | TSSOP | PW | 20 | 2000 | 367.0 | 367.0 | 38.0 | |

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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